

**Amendments to the Specification:**

Please replace the title as follows:

~~RECTIFYING DEVICE AND ELECTRONIC CIRCUIT EMPLOYING SAME, AND~~  
~~PROCESS FOR PRODUCING RECTIFYING DEVICE~~  
RECTIFYING DEVICE, ELECTRONIC CIRCUIT USING THE SAME, AND METHOD  
OF MANUFACTURING RECTIFYING DEVICE

Please replace the paragraph beginning on page 123, line 5, with the following rewritten paragraph:

An aluminum electrode 3 serving as a main electrode was formed in advance on a silicon wafer ~~(not shown)~~ (available from Advantech Co., Ltd, 76.2 mm $\Phi$  (diameter of 3 inches), thickness of 380  $\mu$ m, thickness of a surface oxide film of 1  $\mu$ m) serving as a substrate. An alumina ( $\text{Al}_2\text{O}_3$ ) layer 4 for forming a barrier was laminated by means of deposition on the aluminum electrode 3.